



N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
30V	$5.5 \text{m}\Omega$ @ $V_{GS} = 10V$	75A
	$8.5 \text{m}\Omega @ V_{GS} = 4.5 \text{V}$	50A

Features and Benefits

- Low R_{DS(ON)} Ensures On-State Losses are Minimized
- Excellent Q_{gd} x R_{DS(ON)} Product (FOM)
- Small Form Factor Thermally Efficient Package Enables Higher-Density End Products
- Occupies just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- 100% UIS (Avalanche) Rated
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMTH3004LFGQ</u>)

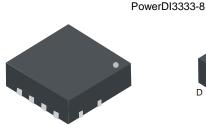
Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

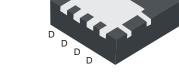
- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

Mechanical Data

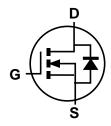
- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208e3
- Weight: 0.072 grams (Approximate)



Top View



1 8 7 6 5 5



Top View

Equivalent Circuit

Ordering Information (Note 4)

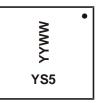
Part Number	Case	Packaging		
DMTH3004LFG-7	PowerDI3333-8	2,000/Tape & Reel		
DMTH3004LFG-13	PowerDI3333-8	3,000/Tape & Reel		

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Bottom View

Marking Information



YS5 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)



Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	30	V	
Gate-Source Voltage	V _{GSS}	±16	V	
Continuous Drain Current (Notes 6 & 9) V _{GS} = 10V	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	I _D	75 52	А
Continuous Drain Current (Note 5) V _{GS} = 10V	$T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$	I _D	15 10	А
Maximum Continuous Body Diode Forward Current (Note 5)	Is	3	A	
Pulsed Drain Current (100µs Pulse, Duty Cycle = 1%)	I _{DM}	250	A	
Pulsed Body Diode Forward Current (100µs Pulse, Duty Cycl	I _{SM}	250	A	
Avalanche Current, L = 0.3mH	I _{AS}	27	A	
Avalanche Energy, L = 0.3mH	E _{AS}	110	mJ	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	$T_{C} = +25^{\circ}C$	P_{D}	50	W
Thermal Resistance, Junction to Case (Note 6)		$R_{ heta JC}$	3	°C/W
Total Power Dissipation (Note 5)	T _A = +25°C	P_{D}	2.5	W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{ heta JA}$	60	°C/W
Operating and Storage Temperature Range		$T_{J_1}T_{STG}$	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

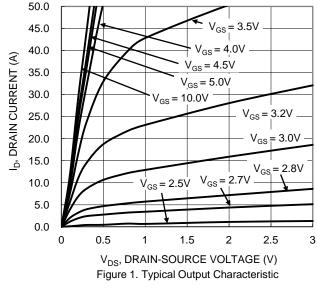
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	V _{DS} = 24V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}		_	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	$V_{GS(TH)}$	1	_	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance		_	4.1	5.5	•	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	6.2	8.5	mΩ	$V_{GS} = 4.5V, I_D = 7A$	
Diode Forward Voltage	V_{SD}	_	0.7	1	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 8)						•	
Input Capacitance	C _{iss}		2370	_		V _{DS} = 15V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss	_	1360	_	pF		
Reverse Transfer Capacitance	Crss	_	240	_			
Gate Resistance	R_g	_	0.6	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	20	_	15/1		
Total Gate Charge (V _{GS} = 10V)	Qg	_	44	_			
Gate-Source Charge	Q _{qs}	_	7	_	nC	$V_{DS} = 15V, I_{D} = 20A$	
Gate-Drain Charge	Q _{gd}	_	8	_		ļ	
Turn-On Delay Time	t _{D(ON)}	_	6.2	_		$V_{DD} = 15V, V_{GS} = 10V,$ $R_{L} = 0.75\Omega, R_{g} = 3\Omega, I_{D} = 20A$	
Turn-On Rise Time	t _R		4.3	_			
Turn-Off Delay Time	t _{D(OFF)}	_	21	_	ns		
Turn-Off Fall Time	t _F		8	_			
Body Diode Reverse Recovery Time	t _{RR}		25	_	ns	1 454 4:/44 5004/	
Body Diode Reverse Recovery Charge	Q_{RR}	_	37	_	nC	$I_F = 15A$, di/dt = 500A/ μ s	

5. R_{0JA} is determined with the device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. R_{0JC} is guaranteed by design while Notes: $R_{\theta JA}$ is determined by the user's board design.

- 6. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 7. Short duration pulse test used to minimize self-heating effect.
- Guaranteed by design. Not subject to product testing.
 Package limited.







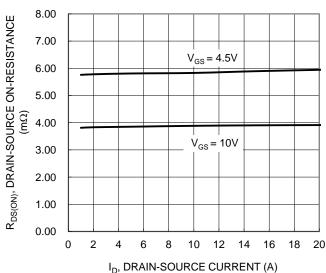


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

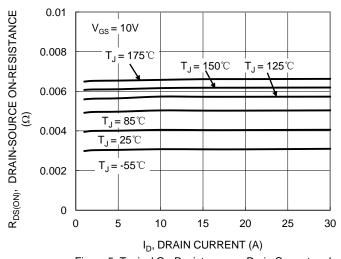


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

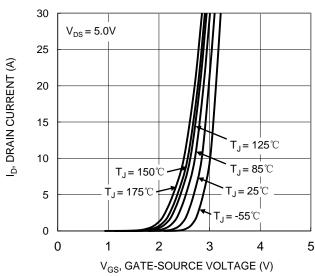


Figure 2. Typical Transfer Characteristic

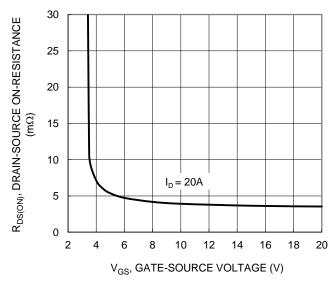


Figure 4. Typical Transfer Characteristic

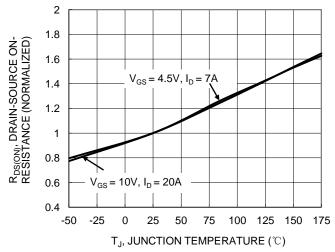


Figure 6. On-Resistance Variation with Temperature





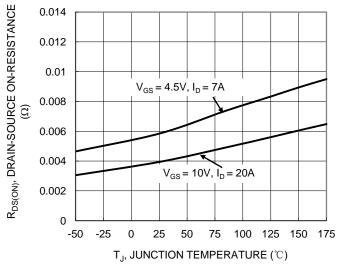


Figure 7. On-Resistance Variation with Temperature

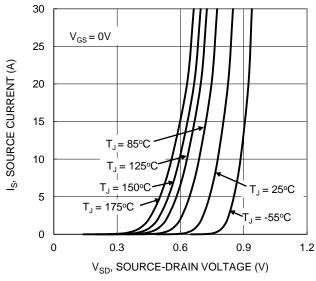


Figure 9. Diode Forward Voltage vs. Current

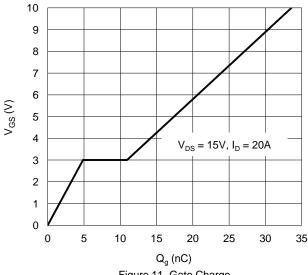


Figure 11. Gate Charge

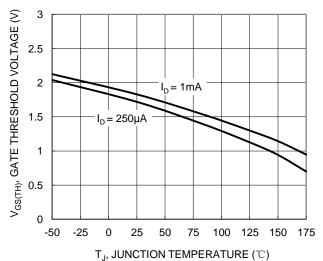


Figure 8. Gate Threshold Variation vs. Junction Temperature

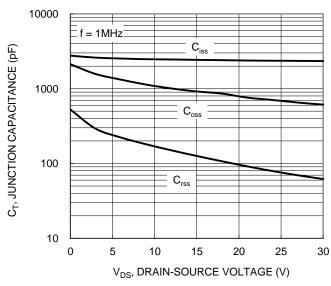


Figure 10. Typical Junction Capacitance

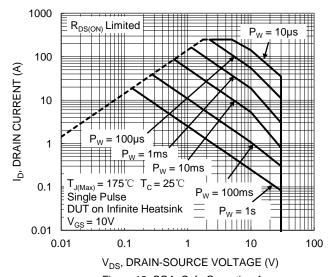


Figure 12. SOA, Safe Operation Area



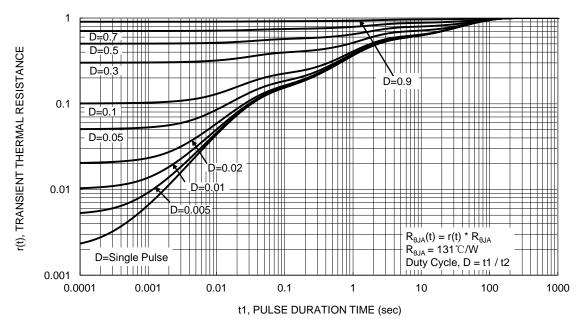


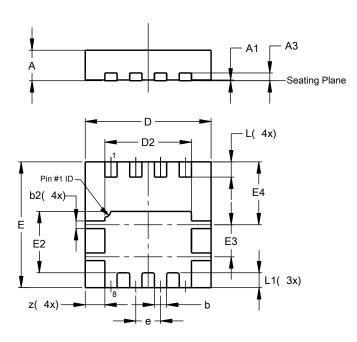
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8

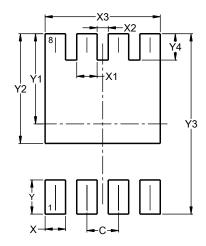


PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3		ı	0.203		
b	0.27	0.37	0.32		
b2	0.15	0.25	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
Е	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
E4	1.60	1.70	1.65		
е	1	-	0.65		
L	0.35	0.45	0.40		
L1	_	_	0.39		
Z	_	_	0.515		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)		
С	0.650		
Х	0.420		
X1	0.420		
X2	0.230		
Х3	2.370		
Y	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		
Y4	0.540		



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